



FIG. 1: Tunneling DOS of lead. Taken from H. Suderow, et al., Physica C, vol. 369, pp. 106 (2002).

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## Problem set - 1

due: Friday Oct 11th by 5pm.

### 1. Electronic heat capacity of a metal.

Approximate the density of states of a metal,  $\rho(\epsilon_{\vec{k}}) = \rho_0$ , as constant for  $\epsilon(\epsilon_{\vec{k}} \geq 0)$ , with no negative energy states.

(a) Write down the integral that describes the energy of an electron gas with Fermi energy  $E_F$ , at a low temperature  $T \ll E_F$ , and filling a volume  $V$ .

(b) What is the heat capacity of the electron gas to leading order in temperature?

For the above you could use geometric arguments, or the Sommerfeld expansion which is described in a note posted on the website.

### 2. Electronic heat capacity of a superconductor.

The low-T energy spectrum of a metal which turns superconducting is unique. A gap opens up about the fermi surface, and the excitations of the superconductor are bogolubov quasiparticles, that could appear in any of the electronic original  $k$ -states. The excitation energies of the Bogolubov quasiparticles (BQP's) are:

$$E_{\vec{k}} = \sqrt{\Delta^2 + (\epsilon_{\vec{k}} - E_F)^2} \quad (1)$$

Each  $k$ -state supports two degenerate Bogolubov quasiparticles due to spin.  $\epsilon_{\vec{k}}$  is the kinetic energy of unpaired electrons at momentum  $\vec{k}$ .

Within the semi-conductor model of superconductors, we think of the BQP's with  $\epsilon_{\vec{k}} > E_F$  as electronic excitations - not so different then just excited electrons. The BQP's with  $\epsilon_{\vec{k}} < E_F$  we think of as hole excitations in an otherwise filled Fermi sea. This implies thinking of the superconductor as if it is a semiconductor for the electronic energies being:

$$\tilde{\epsilon}_{\vec{k}} = \begin{cases} E_F + \sqrt{\Delta^2 + (\epsilon_{\vec{k}} - E_F)^2} & \epsilon_{\vec{k}} > E_F \\ E_F - \sqrt{\Delta^2 + (\epsilon_{\vec{k}} - E_F)^2} & \epsilon_{\vec{k}} < E_F \end{cases} \quad (2)$$

(a) Show that the effective electronic energy for the semiconductor model, Eq. (2), reduces to the bare electronic kinetic energy when  $\Delta \rightarrow 0$ .

- (b) Approximate the metallic density of states (in the absence of superconductivity),  $\rho(\epsilon_{\vec{k}}) = \rho_0$ , as constant. Show that the DOS of the superconductor is given by:

$$\rho(E) = \begin{cases} 0 & |E| < \Delta \\ \rho_0 \frac{|E|}{\sqrt{E^2 - \Delta^2}} & |E| \geq \Delta \end{cases}. \quad (3)$$

- (c) (ungraded) The density of states is directly measurable using tunneling experiments. In these experiments the differential conductance,  $\frac{dI}{dV}$  is measured as a function of tunneling voltage  $V$ . The conductivity is linearly proportional to the DOS at energy  $eV$ . Plot the density of states you obtained above, and compare it to Fig. 1.
- (d) Use the FD distribution to find an expression for the energy stored in the electronic states assuming  $T \ll \Delta$ . You can leave the answer in integral form. Assume that  $\rho_0$  describes the bare density of states of the electrons (in the absence of superconductivity) as long as  $\epsilon_{\vec{k}} > 0$ .
- (e) What is the electronic heat capacity of the superconductor? Find the leading behavior of the heat capacity as a function of temperature upto numerical factors. Hint: check that only the regions of the spectrum closest to the fermi-energy contribute.
3. (Optional review problem) The degeneracy pressure of a Fermi gas. Consider a 3d box of volume  $V$  with free electrons of density  $n$ . What is the pressure the electrons exert on the edges of the box at  $T = 0$ ? Recall that the grand canonical potential is given by:  $-pV = -T \ln \mathcal{Z}$  where  $\mathcal{Z} = \prod_{\vec{k}, \sigma} \mathcal{Z}_k$  is the grand canonical ensemble partition function.